LOW DROPOUT VOLTAGE REGULATOR

■ GENERAL DESCRIPTION

The NJM2871/A, NJM2872/A are low dropout voltage regulators designed for cellular phone application.
Advanced Bipolar technology achieves low noise, high ripple rejection and low quiescent current.

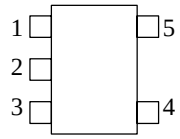
■ PACKAGE OUTLINE

NJM2871F/AF
NJM2872F/AF

■ FEATURES

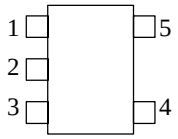
- ●High Ripple Rejection 70dB typ. (f=1kHz)
- ●Output Noise Voltage Vno=30μVrms (Cp=0.01μF)
- ●Output capacitor with 1.0uF ceramic capacitor (Vo≥2.7V)
- ●Output Current Io(max.)=150mA
- ●High Precision Output Vo±2%
  Vo±1%:A Version
- ●Low Dropout Voltage 0.10V typ. (Io=60mA)
- ●ON/OFF Control (Active High)
- ●Operating Voltage Range +2.5V~+14V (Vo≤2.0V version)
- ●Internal Short Circuit Current Limit
- ●Internal Thermal Overload Protection
- ●Bipolar Technology
- ●Package Outline MTP5 (MTP5:2.8×2.9×1.1mm)

■ PIN CONFIGURATION



NJM2871F/AF

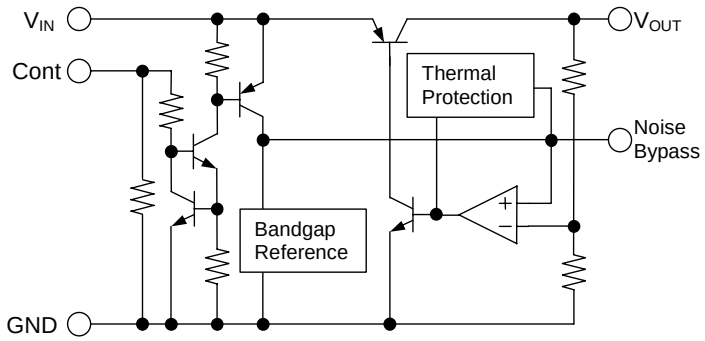
PIN FUNCTION
1. CONTROL (Active High)
2. GND
3. NOISE BYPASS
4. V_{OUT}
5. V_{IN}



NJM2872F/AF

PIN FUNCTION
1.V_{IN}
2.GND
3.CONTROL (Active High)
4.NOISE BYPASS
5.V_{OUT}

■ EQUIVALENT CIRCUIT



■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V_{IN}	+14	V
Control Voltage	V_{CONT}	+14(note 1)	V
Power Dissipation	P_D	200	mW
Operating Temperature	Topr	–40 ~ +85	°C
Storage Temperature	Tstg	–40 ~ +125	°C

(note 1) When input voltage is less than +14V, the absolute maximum control voltage is equal to the input voltage.

■ ELECTRICAL CHARACTERISTICS

(Vo>2.0V version : V_{IN}=Vo+1V, C_{IN}=0.1µF, Co=1.0uF: Vo≥2.7V (Co=2.2uF: Vo≤2.6V), Cp=0.01µF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	Io=30mA	-2%	–	+2%	V
		Io=30mA, A Version	-1%	–	+1%	V
Quiescent Current	I_Q	Io=0mA, expect Icont	–	120	180	µA
Quiescent Current at Control OFF	$I_{Q(OFF)}$	V_{CONT}=0V	–	–	100	nA
Output Current	Io	Vo–0.3V	150	200	-	mA
Line Regulation	$\Delta Vo/\Delta V_{IN}$	V_{IN}=Vo+1V ~ Vo+6V, Io=30mA	–	–	0.10	%/V
Load Regulation	$\Delta Vo/\Delta Io$	Io=0 ~ 100mA	–	–	0.03	%/mA
Dropout Voltage	ΔV_{I-O}	Io=60mA	–	0.10	0.18	V
Ripple Rejection	RR	ein=200mVrms,f=1kHz, Io=10mA V_{IN}=Vo+1V, Vo=3V Version	–	70	–	dB
Average Temperature Coefficient of Output Voltage	$\Delta Vo/\Delta Ta$	Ta=0~85°C, Io=10mA, Vo=3V Version	–	0.2	–	mV/°C
Output Noise Voltage	V_{NO}	f=10Hz~80kHz, Io=10mA, Vo=3V Version	–	30	–	µVrms
Control Voltage for ON-state	$V_{CONT(ON)}$		1.6	–	–	V
Control Voltage for OFF-state	$V_{CONT(OFF)}$		–	–	0.6	V

(Vo≤2.0V version : V_{IN}=Vo+1V, C_{IN}=0.1µF, Co=4.7uF, Cp=0.01µF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	Io=30mA	-2%	–	+2%	V
		Io=30mA, A Version	-1%	–	+1%	V
Quiescent Current	I_Q	Io=0mA, expect Icont	–	120	180	µA
Quiescent Current at Control OFF	$I_{Q(OFF)}$	V_{CONT}=0V	–	–	100	nA
Output Current	Io	Vo–0.3V	150	200	-	mA
Line Regulation	$\Delta Vo/\Delta V_{IN}$	V_{IN}=Vo+1V ~ Vo+6V, Io=30mA	–	–	0.10	%/V
Load Regulation	$\Delta Vo/\Delta Io$	Io=0 ~ 100mA	–	–	0.03	%/mA
Ripple Rejection	RR	ein=200mVrms,f=1kHz, Io=10mA V_{IN}=Vo+1V, Vo=1.8V Version	–	75	–	dB
Average Temperature Coefficient of Output Voltage	$\Delta Vo/\Delta Ta$	Ta=0~85°C, Io=10mA, Vo=1.8V Version	–	0.13	–	mV/°C
Output Noise Voltage	V_{NO}	f=10Hz~80kHz, Io=10mA, Vo=1.8V Version	–	22	–	µVrms
Control Voltage for ON-state	$V_{CONT(ON)}$		1.6	–	–	V
Control Voltage for OFF-state	$V_{CONT(OFF)}$		–	–	0.6	V

(note 2) The above specification is a common specification for all output voltages.
Therefore, it may be different from the individual specification for a specific output voltage.

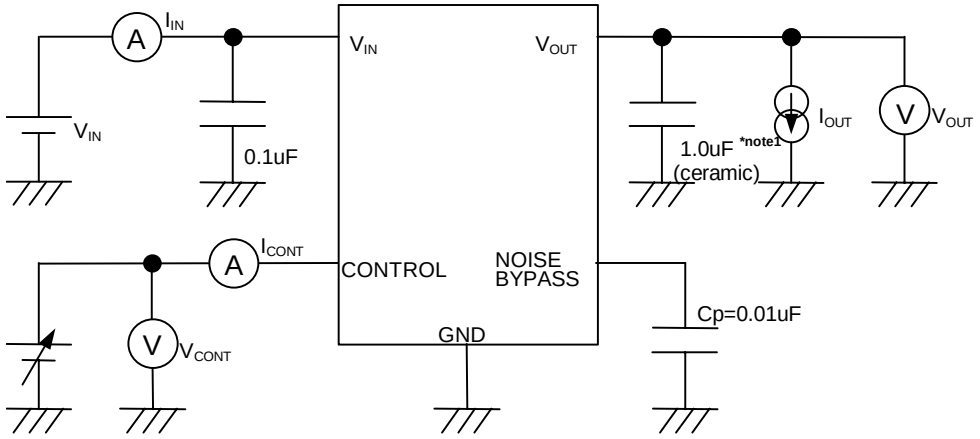
■ OUTPUT VOLTAGE RANK LIST

Device Name	V_{OUT}
NJM287××15	1.5V
NJM287××18	1.8V
NJM287××21	2.1V
NJM287××25	2.5V
NJM287××26	2.6V
NJM287××27	2.7V
NJM287××28	2.8V

Device Name	V_{OUT}
NJM287××285	2.85V
NJM287××29	2.9V
NJM287××03	3.0V
NJM287××31	3.1V
NJM287××32	3.2V
NJM287××33	3.3V
NJM287××34	3.4V

Device Name	V_{OUT}
NJM287××35	3.5V
NJM287××38	3.8V
NJM287××04	4.0V
NJM287××05	5.0V

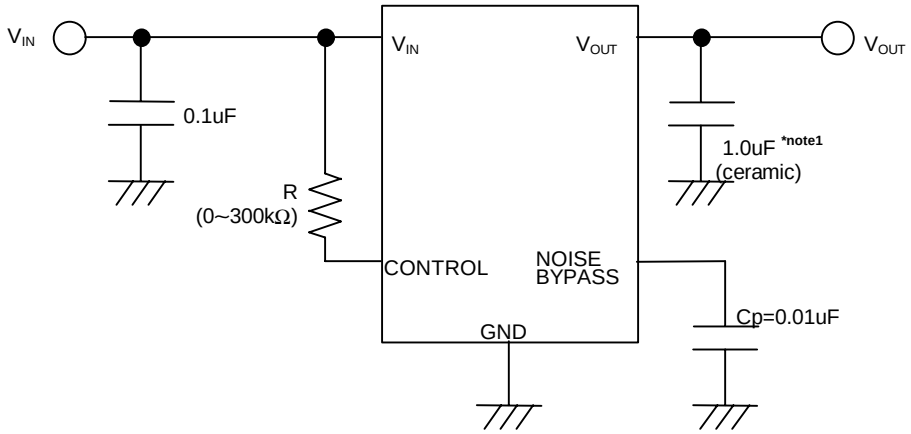
■ TEST CIRCUIT



*note1 2.0V < Vo ≤ 2.6V version : Co=2.2uF(ceramic)
Vo ≤ 2.0V version : Co=4.7uF(ceramic)

■ TYPICAL APPLICATION

① In case that ON/OFF Control is not required:

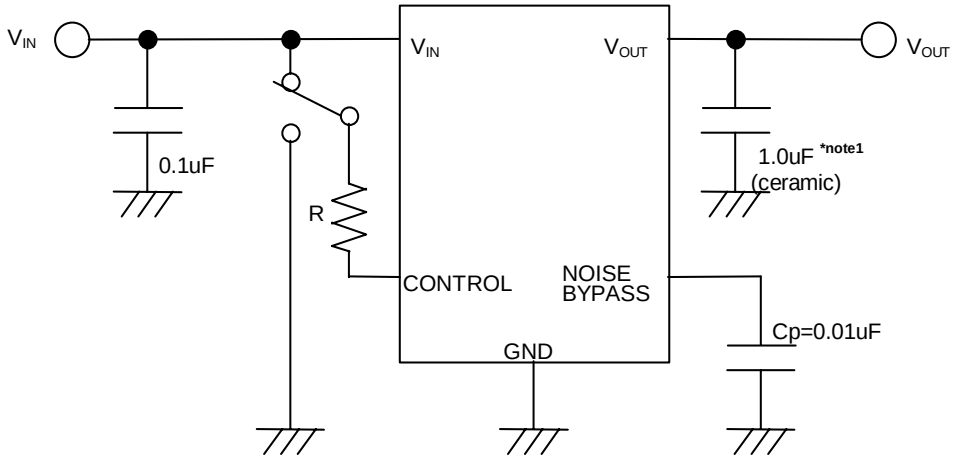


*note1 2.0V < Vo ≤ 2.6V version : Co=2.2uF(ceramic)
Vo ≤ 2.0V version : Co=4.7uF(ceramic)

Connect control terminal to V_{IN} terminal

The quiescent current can be reduced by using a resistance "R". Instead, it increases the minimum operating voltage. For further information, please refer to Figure "Output Voltage vs. Control Voltage".

② In use of ON/OFF CONTROL:



*note1 2.0V < Vo ≤ 2.6V version : Co=2.2uF(ceramic)
Vo ≤ 2.0V version : Co=4.7uF(ceramic)

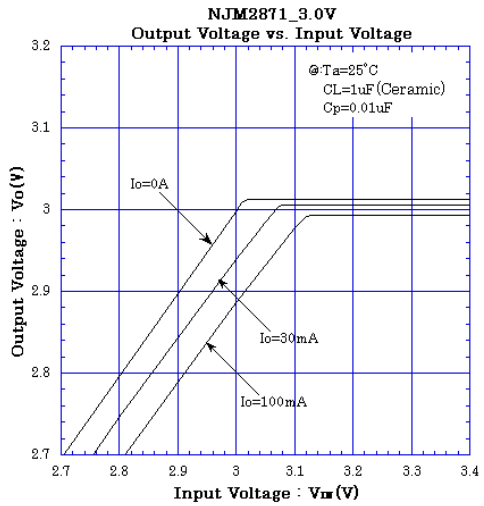
State of control terminal:

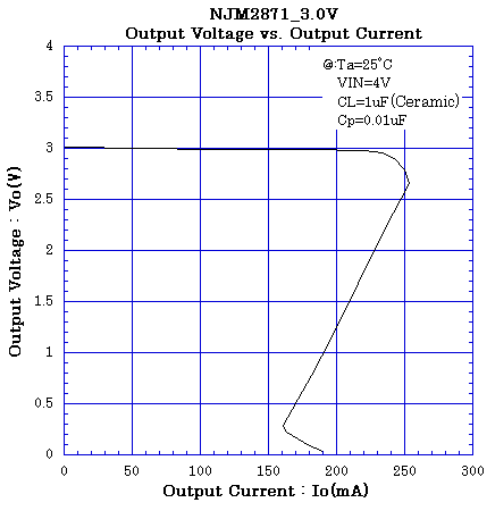
- "H"→ output is enabled.
- "L" or "open" → output is disabled.

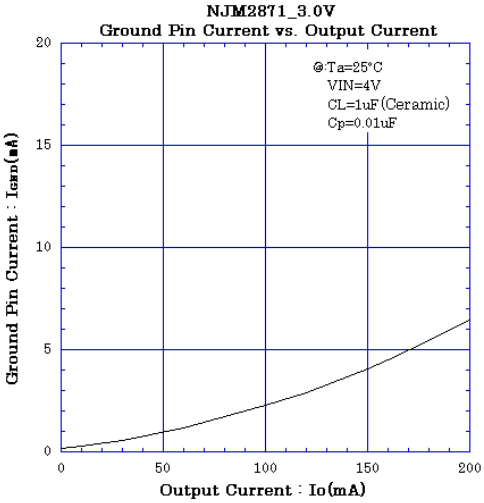
✶Noise bypass Capacitance Cp

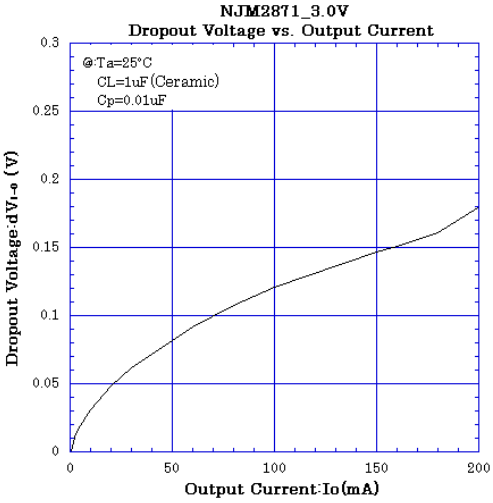
Noise bypass capacitance Cp reduces noise generated by band-gap reference circuit.
Noise level and ripple rejection will be improved when larger Cp is used.
Use of smaller Cp value may cause oscillation.
Use the Cp value of 0.01uF greater to avoid the problem.

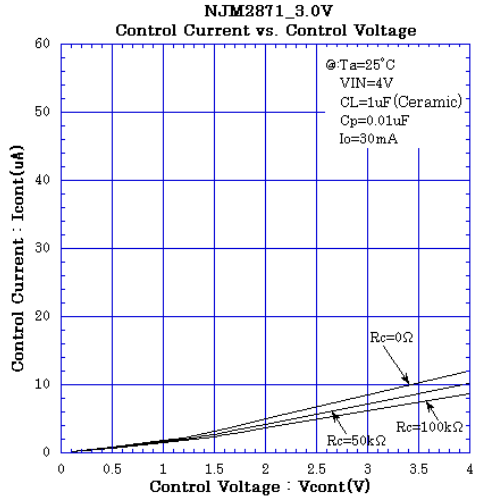
■ ELECTRICAL CHARACTERISTICS

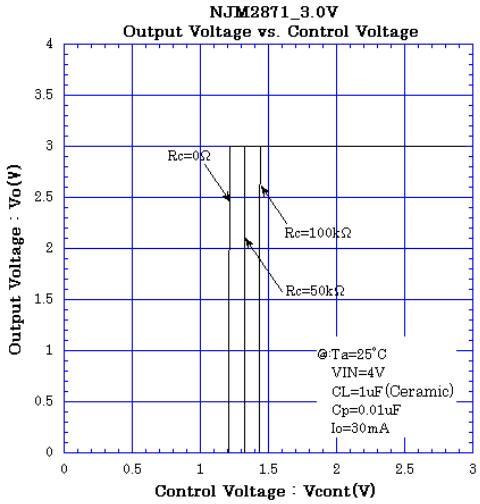




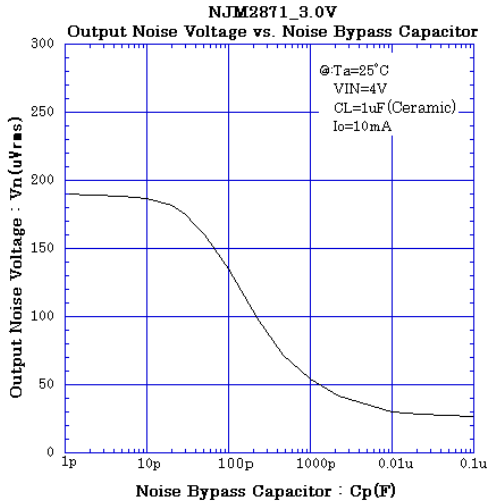


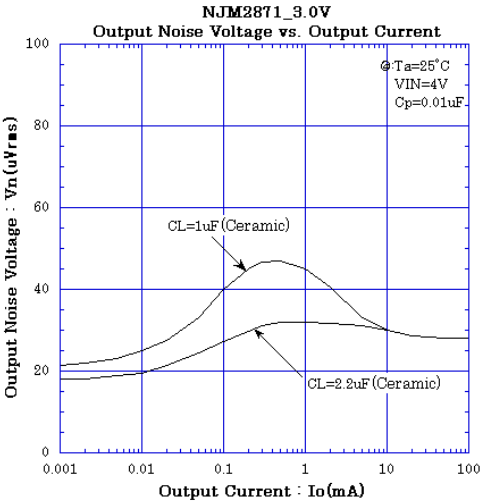


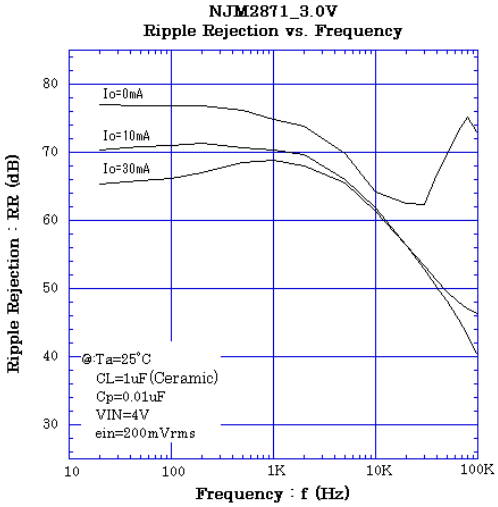


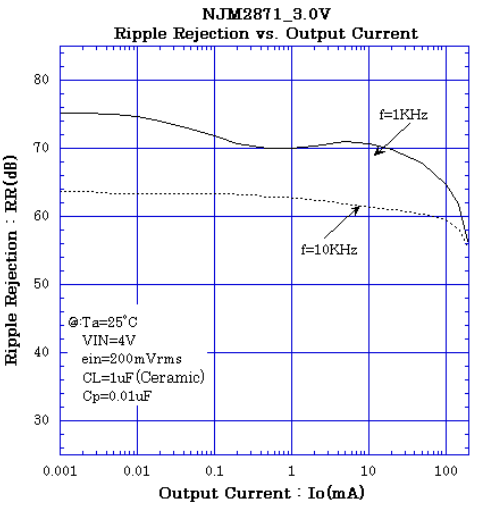


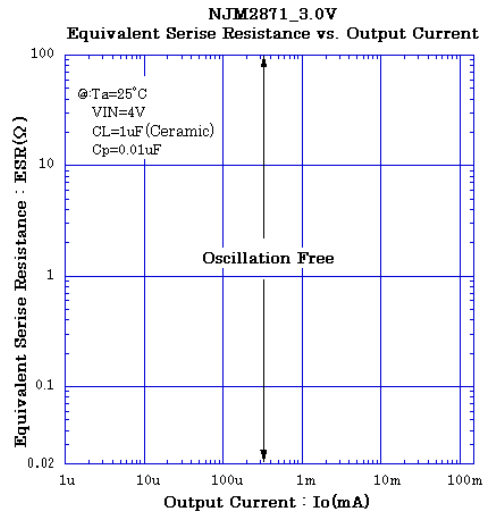
■ ELECTRICAL CHARACTERISTICS











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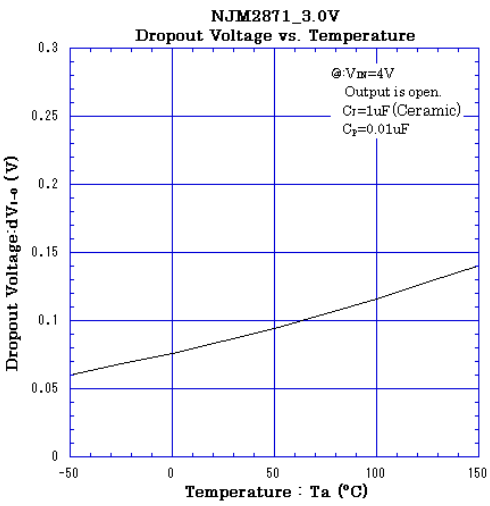

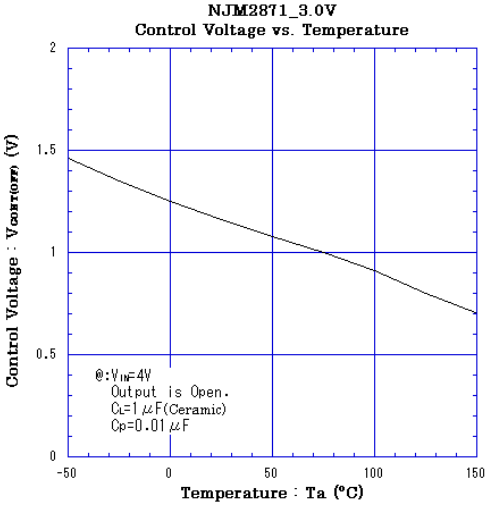

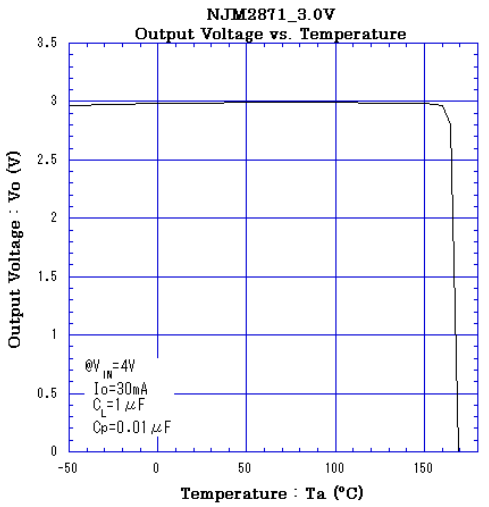

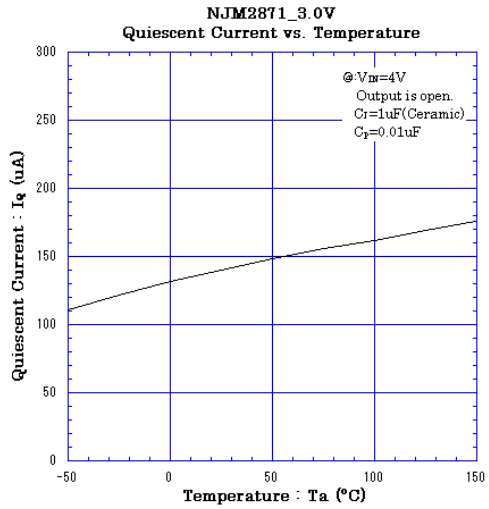

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